

Features, Benefits and Applications

- The world's lowest power programmable oscillator with 3.2 mA typical active current
- 1-110 MHz frequency range
- LVCMOS/LVTTL compatible output
- Frequency stability as low as ±20 PPM
- Standby current as low as 0.5 µA
- Fast resume time of 3.0 ms typical
- Standby or output enable modes
- Four industry-standard packages: 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm
- Outstanding mechanical robustness for portable applications
- All-silicon device with outstanding reliability of 2 FIT (10x improvement over quartz-based devices), enhancing system mean-time-to-failure (MTBF)
- Ultra short lead time
- Ideal for portable applications: portable media players, digital cameras, digital camcorders, portable navigation devices, handheld gaming, cell phones and other battery-powered handheld applications
- Ideal for high-speed serial protocols such as: USB 1.1, USB 2.0, USB 3.0, SATA, SAS, Firewire, Ethernet, etc.

Specifications

Electrical Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Output Frequency Range	f	1	-	110	MHz		
Frequency Stability	F_stab	-20	-	+20	PPM	Inclusive of: Initial stability, operating temperature, rated power,	
,		-25	-	+25	PPM	supply voltage change, load change, shock and vibration	
		-30	-	+30	PPM	± 20 PPM available in extended commercial temperature only	
		-50	-	+50	PPM		
Aging	Ag	-1.0	-	1.0	PPM	1st year at 25°C	
Operating Temperature Range	T_use	-20	-	+70	°C	Extended Commercial	
		-40	-	+85	°C	Industrial	
Supply Voltage	Vdd	1.71	1.8	1.89	V		
11,5 0		2.25	2.5	2.75	V		
		2.52	2.8	3.08	V		
		2.97	3.3	3.63	V		
Current Consumption	ldd	_	3.7	4.1	mA	No load condition, f = 20 MHz, Vdd = 2.5 V, 2.8 V or 3.3 V	
·		-	3.2	3.5	mA	No load condition, f = 20 MHz, Vdd = 1.8 V	
Standby Current	I_std	_	2.4	4.3	μA	ST = GND, Vdd = 3.3 V, Output is Weakly Pulled Down	
		_	1.2	2.2	μA	ST = GND, Vdd = 2.5 or 2.8 V, Output is Weakly Pulled Down	
		_	0.4	0.8	μA	ST = GND, Vdd = 1.8 V, Output is Weakly Pulled Down	
Duty Cycle	DC						
		40	50	60	%	All Vdds. f > 75 MHz	
Rise/Fall Time	Tr, Tf	_	1	2	ns	20% - 80% Vdd=2.5 V, 2.8 V or 3.3 V, 15 pf load	
		-	1.3	2.5	ns	20% - 80% Vdd=1.8 V, 15 pf load	
Output Voltage High	VOH	90%	_	-	Vdd	IOH = -4 mA (Vdd = 3.3 V) IOH = -3 mA (Vdd = 2.8 V and Vdd = 2.5 V) IOH = -2 mA (Vdd = 1.8 V)	
Output Voltage Low	VOL	-	-	10%	Vdd	IOL = 4 mA (Vdd = 3.3 V) IOL = 3 mA (Vdd = 2.8 V and Vdd = 2.5 V) IOL = 2 mA (Vdd = 1.8 V)	
Output Load	Ld	-	-	15	pF	At maximum frequency and supply voltage. Contact SiTime for higher output load option	
Input Voltage High	VIH	70%	-	-	Vdd	Pin 1, OE or ST	
Input Voltage Low	VIL	-	-	30%	Vdd	Pin 1, OE or ST	
Startup Time	T_osc	-	-	10	ms	Measured from the time Vdd reaches its rated minimum value	
Resume Time	T_resume	-	3.0	3.8	ms	Measured from the time ST pin crosses 50% threshold	
RMS Period Jitter		-	-	4.0	ps	f = 75 MHz, Vdd = 2.5 V, 2.8 V or 3.3 V	
		-	-	5.5	ps	f = 75 MHz, Vdd = 1.8 V	
RMS Phase Jitter (random)	T_phj	-	0.6	-	ps	f = 75 MHz, Integration bandwidth = 900 kHz to 7.5 MHz, VDD = 2.5 V, 2.8 V, or 3.3 V	
		-	0.8	-	ps	f = 75 MHz, Integration bandwidth = 900 kHz to 7.5 MHz, VDD = 1.8 V	



Specifications (Cont.)

Pin Description Tables

Pin #1 Functionality				
OE				
H or Open ^[1] : specified frequency output				
L: output is high impedance				
ST				
H or Open: specified frequency output				
L: output is low level (weak pull down). Oscillation stops				

Pin Map				
Pin	Connection			
1	OE/ST			
2	GND			
3	CLK			
4	VDD			

Absolute Maximum Table

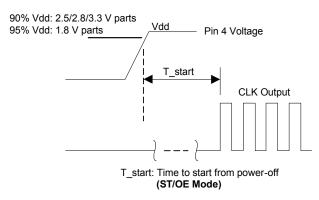
Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

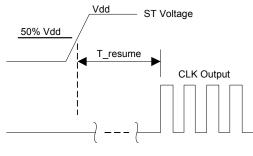
Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	4	V
Electrostatic Discharge	-	2000	V
Theta JA (with copper plane on VDD and GND)	-	75	°C/W
Theta JC (with PCB traces of 0.010 inch to all pins)	-	24	°C/W
Soldering Temperature (follow standard Pb free soldering guidelines)	-	260	°C
Number of Program Writes	-	1	NA
Program Retention over -40 to 125°C, Process, VDD (0 to 3.65 V)	1,000+	_	years

Environmental Compliance

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL1 @ 260°C

Startup and Resume Timing Diagram





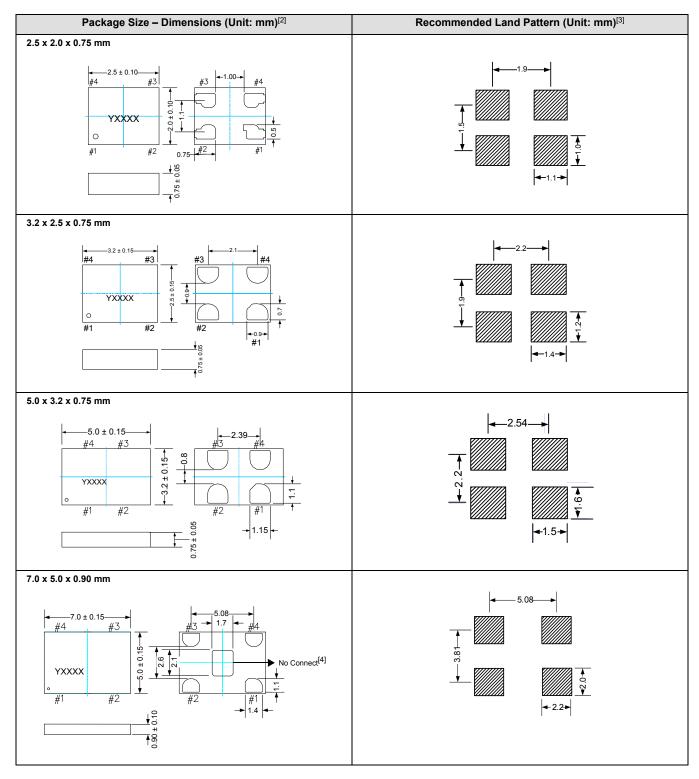
T_resume: Time to resume from ST (ST Mode Only)

Note:

1. In 1.8 V mode, a resistor of <100 k Ω between OE pin and VDD is recommended.



Dimensions and Land Patterns



Notes:

2. Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.

- A capacitor of value 0.1 μF between Vdd and GND is recommended.
 The 7050 package with part number designation "-8" has NO center pad.

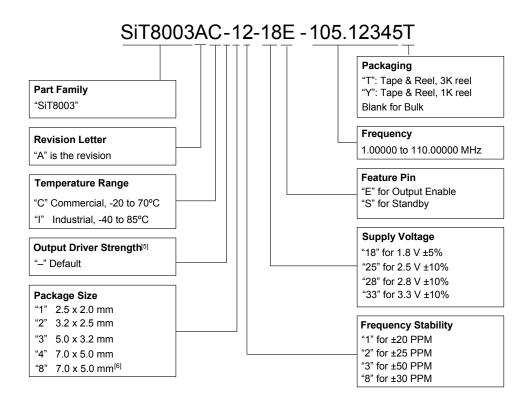
Low Power 1-110 MHz Oscillator



Part No. Guide - How to Order

SiT8003

The Part No. Guide is for reference only. For real-time customization and exact part number, use the SiTime Part Number Generator.



Note:

Contact SiTime for different drive strength options for driving higher loads or reducing EMI.
 Without Center Pad.

Frequency Stability vs. Temperature Range Options

Frequency	Temperature	Supply Voltage				
Stability (PPM)	Range	1.8 V	2.5 V	2.8 V	3.3 V	
±20	C (-20 to +70°C)	\checkmark	\checkmark	\checkmark	\checkmark	
	l (-40 to +85°C)	-	-	-	-	
±25	C (-20 to +70°C) I (-40 to +85°C)	\checkmark	\checkmark	\checkmark	\checkmark	
±30	C (-20 to +70°C) I (-40 to +85°C)	\checkmark	\checkmark	\checkmark	\checkmark	
±50	C (-20 to +70°C) I (-40 to +85°C)	\checkmark	\checkmark	\checkmark	\checkmark	

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